

# INA20x-Q1 車載用グレード、-16V~+80V、ロー/ハイサイド、高速、電圧出力、電流センシング・アンプ、コンパレータおよび基準電圧搭載

## 1 特長

- 車載アプリケーション用に認定済み
- 下記内容でAEC-Q100認定済み
  - デバイス温度グレード1: 動作時周囲温度範囲 -40°C~125°C
  - デバイスHBM ESD分類レベルH2
  - デバイスCDM ESD分類レベルC3B
- 電流センシング・アンプ:
  - 同相範囲: -16V~+80V
  - 温度範囲全体にわたって最大誤差3.5%
  - 帯域幅: 500kHz (INA200-Q1)
  - 3つのゲイン・オプション:
    - 20V/V (INA200-Q1)
    - 50V/V (INA201-Q1)
    - 100V/V (INA202-Q1)
- オープン・ドレインのコンパレータを内蔵
  - ラッチ機能
  - 0.6Vの内部基準電圧
- 静止電流: 1800μA (最大値)
- JESD78準拠で100mAを超えるラッチアップ性能
- パッケージ: VSSOP-8

## 2 アプリケーション

- EPS (電動パワー・ステアリング)システム
- 車体制御モジュール
- ブレーキ・システム
- ESC (横滑り防止装置)システム

## 3 概要

INA200-Q1, INA201-Q1, INA202-Q1 (INA20x-Q1)はローサイドまたはハイサイドの電圧出力電流シャント・モニタです。INA20x-Q1デバイスは、-16Vから+80Vの同相電圧において、シャント両端の電圧低下を感知できます。INA20x-Q1は20V/V、50V/V、100V/Vの3つの出力電圧スケールで、最高500kHzの帯域幅で利用可能です。

また、INA20x-Q1にはオープン・ドレインのコンパレータと内部基準電圧が組み込まれており、0.6Vのスレッシュホールドを実現します。外部の分割抵抗により、電流トリップ点を設定します。コンパレータにはラッチ機能があり、RESETピンをグランドに接続(またはオープンに保持)することで透過的にできます。

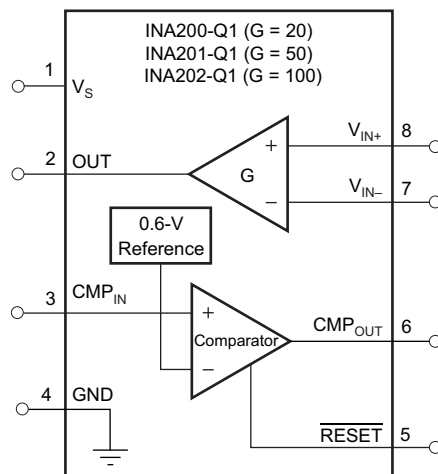
INA20x-Q1は2.7V~18Vの単一電源で動作し、消費電流は最大1800μAです。これらのデバイスは、超小型VSSOP-8パッケージで供給されます。すべてのデバイスは、-40°C~+125°Cの動作温度範囲で動作します。

### 製品情報<sup>(1)</sup>

型番	パッケージ	本体サイズ(typ)
INA200-Q1	VSSOP (8)	3.00mm×3.00mm
INA201-Q1		
INA202-Q1		

(1) 利用可能なすべてのパッケージについては、このデータシートの末尾にあるパッケージ・オプションについての付録を参照してください。

### 概略回路図



## 目次

1	特長	1	9.1	Overview	12
2	アプリケーション	1	9.2	Functional Block Diagram	12
3	概要	1	9.3	Feature Description	13
4	改訂履歴	2	9.4	Device Functional Modes	13
5	Device Comparison Table	3	10	Application Information	14
6	Pin Configuration and Functions	3	10.1	Application Information	14
7	Specifications	4	10.2	Typical Applications	18
7.1	Absolute Maximum Ratings	4	11	Power Supply Recommendations	22
7.2	ESD Ratings	4	12	Layout	22
7.3	Recommended Operating Conditions	4	12.1	Layout Guidelines	22
7.4	Thermal Information	4	12.2	Layout Example	22
7.5	Electrical Characteristics: Current-Shunt Monitor	5	13	デバイスおよびドキュメントのサポート	23
7.6	Electrical Characteristics: Comparator	6	13.1	関連リンク	23
7.7	Electrical Characteristics: General	6	13.2	コミュニティ・リソース	23
7.8	Typical Characteristics	7	13.3	商標	23
8	Parameter Measurement Information	11	13.4	静電気放電に関する注意事項	23
8.1	Hysteresis	11	13.5	Glossary	23
9	Detailed Description	12	14	メカニカル、パッケージ、および注文情報	23

## 4 改訂履歴

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

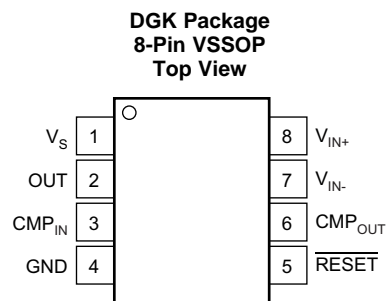
Revision B (November 2012) から Revision C に変更	Page
• 「製品情報」セクション、「ESD定格」表、「熱に関する情報」表、「機能説明」セクション、「デバイスの機能モード」セクション、「アプリケーションと実装」セクション、「電源に関する推奨事項」セクション、「レイアウト」セクション、「デバイスおよびドキュメントのサポート」セクション、「メカニカル、パッケージ、および注文情報」セクションを追加	1
• データシートのタイトルを更新	1
• 「特長」の箇条書きを明確化のため更新	1
• データシート全体で業界標準用語に合わせてMSOPをVSSOPに変更	1
• 「アプリケーション」の箇条書きを更新	1
• 「概要」セクションの文章を明確化のため更新	1
• データシートのすべての図にQ1デバイス名を追記	1
• Changed pin names in Absolute Maximum Ratings to show correct names	4
• Added Operating Temperature to <i>Absolute Maximum Ratings</i> table	4
• Changed CMP $V_{OUT}$ to $CMP_{OUT}$ in <i>large-signal differential voltage gain</i> parameter condition	6
• Deleted package name from Figure 27	15
• Changed Figure 28 caption	15
• Changed text from " $R_{FILT} - 3\%$ " to " $R_{FILT} + 3\%$ " in 2nd paragraph of <i>Input Filtering</i> section	15
• Changed 22-k $\Omega$ $R_1$ resistor to $R_3$ in Figure 31	18

Revision A (September 2012) から Revision B に変更	Page
• 混在製造ステータスを量産用データに変更	1
• デバイスの図をペアからシングルに変更	1
• 「特長」の箇条書きにAEC-Q100の情報を追加	1
• 「アプリケーション」の箇条書きを更新	1
• Removed D package from pin configuration image.	4

## 5 Device Comparison Table

DEVICE	DESCRIPTION
<a href="#">INA193A-Q1</a>	Same amplifier performance as INA200-Q1 without integrated comparator
<a href="#">INA203-Q1</a>	Dual comparator alternative to the INA200-Q1 single comparator
<a href="#">INA282-Q1</a>	Automotive, 80-V, bidirectional, high-accuracy, low- or high-side, voltage out current shunt monitor
<a href="#">INA300-Q1</a>	Automotive, 36-V, low- or high-side, overcurrent protection comparator
<a href="#">INA301</a>	Overcurrent protection, high-speed, precision, current sense amplifier with integrated comparator

## 6 Pin Configuration and Functions



### Pin Functions

PIN		I/O	DESCRIPTION
NO.	NAME		
1	$V_S$	Analog	Power supply
2	OUT	Analog output	Output voltage
3	$CMP_{IN}$	Analog input	Comparator input
4	GND	Analog	Ground
5	$\overline{RESET}$	Analog input	Comparator reset pin, active low
6	$CMP_{OUT}$	Analog output	Comparator output
7	$V_{IN-}$	Analog input	Negative input, connect to shunt low side
8	$V_{IN+}$	Analog input	Positive input, connect to shunt high side

## 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup>

		MIN	MAX	UNIT
Supply voltage, $V_S$		2.7	18	V
Current-shunt monitor analog inputs, $V_{IN+}$ , $V_{IN-}$	Differential ( $V_{IN+} - V_{IN-}$ )	-18	18	V
	Common mode <sup>(2)</sup> , $V_{CM} = (V_{IN+} + V_{IN-}) / 2$	-16	80	V
Comparator analog input and reset pins, $CMP_{IN}$ and $RESET$ <sup>(2)</sup>		GND - 0.3	$(V_S) + 0.3$	V
Analog output, $OUT$ <sup>(2)</sup>		GND - 0.3	$(V_S) + 0.3$	V
Comparator output, $CMP_{OUT}$ <sup>(2)</sup>		GND - 0.3	18	V
Input current into any pin <sup>(2)</sup>			5	mA
Operating temperature, $T_A$		-40	125	°C
Junction temperature			150	°C
Storage temperature, $T_{stg}$		-65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) This voltage may exceed the ratings shown if the current at that pin does not exceed 5 mA.

### 7.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$ Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 <sup>(1)</sup>	±2000	V
	Charged-device model (CDM), per AEC Q100-011	±1000	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

### 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
$V_{CM}$	Common-mode input voltage	-16	12	80	V
$V_S$	Operating supply voltage	2.7	12	18	V
$T_A$	Operating free-air temperature	-40	25	125	°C

### 7.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		INA20x-Q1	UNIT
		DGK (VSSOP)	
		8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	162.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	37.7	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	82.9	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	1.3	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	81.4	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](http://www.ti.com/lit/zip/SRA953).

## 7.5 Electrical Characteristics: Current-Shunt Monitor

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 12\text{ V}$ ,  $V_{CM} = 12\text{ V}$ ,  $V_{SENSE} = V_{IN+} - V_{IN-} = 100\text{ mV}$ ,  $R_L = 10\text{ k}\Omega$  to GND,  $R_{PULL-UP} = 5.1\text{ k}\Omega$  connected from  $CMP_{OUT}$  to  $V_S$ , and  $CMP_{IN} = \text{GND}$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>INPUT</b>						
$V_{SENSE}$	Full-scale sense input voltage	$V_{SENSE} = V_{IN+} - V_{IN-}$		0.15	$(V_S - 0.25) / \text{Gain}$	V
$V_{CM}$	Common-mode input range	$T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$	-16		80	V
CMR	Common-mode rejection	$V_{IN+} = -16\text{ V}$ to $80\text{ V}$	80	100		dB
		$V_{IN+} = 12\text{ V}$ to $80\text{ V}$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$ .	100	123		dB
$V_{OS}$	Offset voltage, RTI <sup>(1)</sup>	$T_A = 25^\circ\text{C}$		$\pm 0.5$	$\pm 2.5$	mV
		$T_A = 25^\circ\text{C}$ to $125^\circ\text{C}$			$\pm 3$	mV
		$T_A = -40^\circ\text{C}$ to $25^\circ\text{C}$			$\pm 3.5$	mV
$dV_{OS}/dT$	Offset voltage, RTI, versus temperature	$T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$		5		$\mu\text{V}/^\circ\text{C}$
PSR	Offset voltage, RTI, versus power supply	$V_{OUT} = 2\text{ V}$ , $V_{IN+} = 18\text{ V}$ , $2.7\text{ V}$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$		2.5	100	$\mu\text{V}/\text{V}$
$I_B$	Input bias current, $V_{IN-}$ Pin	$T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$		$\pm 9$	$\pm 16$	$\mu\text{A}$
<b>OUTPUT (<math>V_{SENSE} \geq 20\text{ mV}</math>)</b>						
G	Gain	INA200-Q1		20		V/V
		INA201-Q1		50		V/V
		INA202-Q1		100		V/V
	Gain error	$V_{SENSE} = 20\text{ mV}$ to $100\text{ mV}$		$\pm 0.2\%$	$\pm 1\%$	
		$V_{SENSE} = 20\text{ mV}$ to $100\text{ mV}$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$			$\pm 2\%$	
	Total output error <sup>(2)</sup>	$V_{SENSE} = 120\text{ mV}$ , $V_S = 16\text{ V}$		$\pm 0.75\%$	$\pm 2.2\%$	
		$V_{SENSE} = 120\text{ mV}$ , $V_S = 16\text{ V}$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$			$\pm 3.5\%$	
	Nonlinearity error <sup>(3)</sup>	$V_{SENSE} = 20\text{ mV}$ to $100\text{ mV}$		$\pm 0.002\%$		
$R_O$	Output impedance			1.5		$\Omega$
$C_{LOAD}$	Maximum capacitive load	No sustained oscillation		10		nF
<b>OUTPUT (<math>V_{SENSE} &lt; 20\text{ mV}</math>)<sup>(4)</sup></b>						
Output		$-16\text{ V} \leq V_{CM} < 0\text{ V}$	INA20x-Q1	300		mV
			INA200-Q1		0.4	V
		$0\text{ V} \leq V_{CM} \leq V_S$ , $V_S = 5\text{ V}$	INA201-Q1		1	V
			INA202-Q1		2	V
		$V_S < V_{CM} \leq 80\text{ V}$	INA20x-Q1	300		mV
<b>VOLTAGE OUTPUT<sup>(5)</sup></b>						
	Output swing to the positive rail	$V_{IN-} = 11\text{ V}$ , $V_{IN+} = 12\text{ V}$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$		$(V_S) - 0.15$	$(V_S) - 0.25$	V
	Output swing to GND <sup>(6)</sup>	$V_{IN-} = 0\text{ V}$ , $V_{IN+} = -0.5\text{ V}$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$		$(V_{GND}) + 0.004$	$(V_{GND}) + 0.05$	V
<b>FREQUENCY RESPONSE</b>						
BW	Bandwidth	$C_{LOAD} = 5\text{ pF}$	INA200-Q1	500		kHz
			INA201-Q1	300		kHz
			INA202-Q1	200		kHz
	Phase margin	$C_{LOAD} < 10\text{ nF}$		40		Degrees
SR	Slew rate			1		V/ $\mu\text{s}$
	Settling time (1%)	$V_{SENSE} = 10\text{ mV}_{PP}$ to $100\text{ mV}_{PP}$ , $C_{LOAD} = 5\text{ pF}$		2		$\mu\text{s}$
<b>NOISE, RTI</b>						
	Voltage noise density			40		nV/ $\sqrt{\text{Hz}}$

(1) Offset is extrapolated from measurements of the output at 20 mV and 100 mV  $V_{SENSE}$ .

(2) Total output error includes effects of gain error and  $V_{OS}$ .

(3) Linearity is best fit to a straight line.

(4) For details on this region of operation, see the [Accuracy Variations](#) section in the [Device Functional Modes](#).

(5) See [Figure 7](#).

(6) Specified by design.

## 7.6 Electrical Characteristics: Comparator

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 12\text{ V}$ ,  $V_{CM} = 12\text{ V}$ ,  $V_{SENSE} = 100\text{ mV}$ ,  $R_L = 10\text{ k}\Omega$  to GND, and  $R_{PULL-UP} = 5.1\text{ k}\Omega$  connected from  $CMP_{OUT}$  to  $V_S$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFFSET VOLTAGE</b>					
Threshold	$T_A = 25^\circ\text{C}$	590	608	620	mV
	$T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$	586		625	mV
Hysteresis <sup>(1)</sup>	$T_A = -40^\circ\text{C}$ to $85^\circ\text{C}$		-8		mV
<b>INPUT BIAS CURRENT<sup>(2)</sup></b>					
$CMP_{IN}$ pin			0.005	10	nA
	$T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$			15	nA
<b>INPUT VOLTAGE RANGE</b>					
$CMP_{IN}$ pin		0 to $V_S - 1.5$			V
<b>OUTPUT (OPEN-DRAIN)</b>					
Large-signal differential voltage gain	$CMP_{OUT} = 1\text{ V}$ to $4\text{ V}$ , $R_L \geq 15\text{ k}\Omega$ connected to $5\text{ V}$		200		V/mV
$I_{LKG}$ High-level leakage current <sup>(3)(4)</sup>	$V_{ID} = 0.4\text{ V}$ , $V_{OH} = V_S$		0.0001	1	$\mu\text{A}$
$V_{OL}$ Low-level output voltage <sup>(3)</sup>	$V_{ID} = -0.6\text{ V}$ , $I_{OL} = 2.35\text{ mA}$		220	300	mV
<b>RESPONSE TIME</b>					
Response time <sup>(5)</sup>	$R_L$ to $5\text{ V}$ , $C_L = 15\text{ pF}$ , 100-mV input step with 5-mV overdrive		1.3		$\mu\text{s}$
<b>RESET</b>					
$\overline{\text{RESET}}$ threshold <sup>(6)</sup>			1.1		V
Logic input impedance			2		$\text{M}\Omega$
Minimum $\overline{\text{RESET}}$ pulse duration			1.5		$\mu\text{s}$
$\overline{\text{RESET}}$ propagation delay			3		$\mu\text{s}$

- (1) Hysteresis refers to the threshold (the threshold specification applies to a rising edge of a noninverting input) of a falling edge on the noninverting input of the comparator; see [Figure 25](#).
- (2) Specified by design.
- (3)  $V_{ID}$  refers to the differential voltage at the comparator inputs.
- (4) Pulling the open-drain output to the range of 2.7 V to 18 V is permissible, regardless of  $V_S$ .
- (5) The comparator response time specified is the interval between the input step function and the instant when the output crosses 1.4 V.
- (6) The  $\overline{\text{RESET}}$  input has an internal 2-M $\Omega$  (typical) pulldown. Leaving  $\overline{\text{RESET}}$  open results in a low state, with transparent comparator operation.

## 7.7 Electrical Characteristics: General

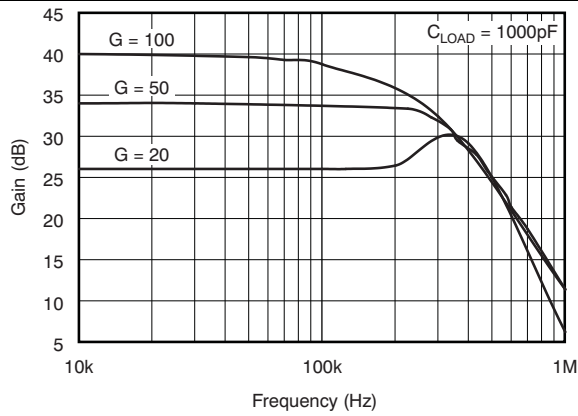
at  $T_A = 25^\circ\text{C}$ ,  $V_S = 12\text{ V}$ ,  $V_{CM} = 12\text{ V}$ ,  $V_{SENSE} = 100\text{ mV}$ ,  $R_L = 10\text{ k}\Omega$  to GND,  $R_{PULL-UP} = 5.1\text{ k}\Omega$  connected from  $CMP_{OUT}$  to  $V_S$ , and  $CMP_{IN} = 1\text{ V}$  (unless otherwise noted)

GENERAL PARAMETERS	CONDITIONS	MIN	TYP	MAX	UNIT
<b>POWER SUPPLY</b>					
$I_Q$ Quiescent current	$V_{OUT} = 2\text{ V}$		1350	1800	$\mu\text{A}$
	$V_{SENSE} = 0\text{ mV}$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$			1850	$\mu\text{A}$
Comparator power-on reset threshold <sup>(1)</sup>			1.5		V

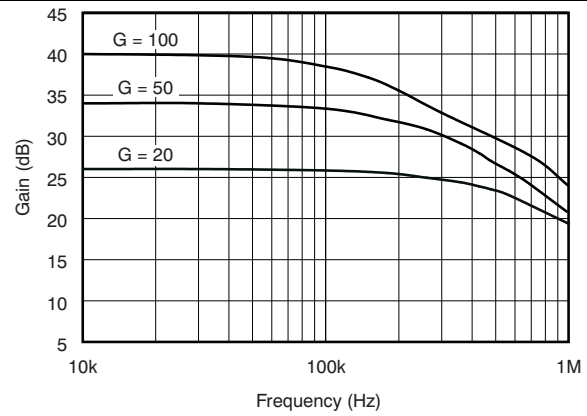
- (1) The INA20x-Q1 devices power up with the comparator in a defined reset state as long as the  $\overline{\text{RESET}}$  pin is open or grounded. The comparator is in reset as long as the power supply is below the voltage shown here. The comparator assumes a state based on the comparator input above this supply voltage. If  $\overline{\text{RESET}}$  is high at power up, the comparator output comes up high and requires a reset to assume a low state, if appropriate.

### 7.8 Typical Characteristics

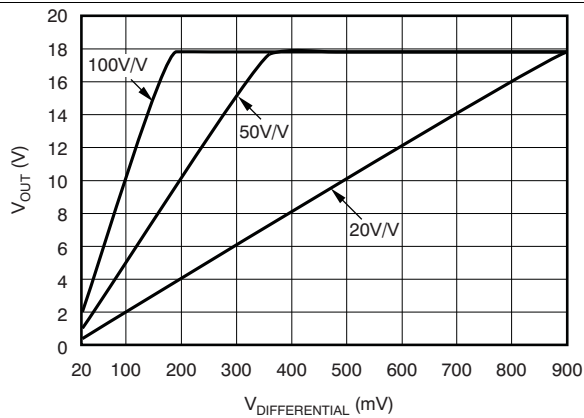
At  $T_A = 25^\circ\text{C}$ ,  $V_S = 12\text{ V}$ ,  $V_{IN+} = 12\text{ V}$ , and  $V_{SENSE} = 100\text{ mV}$  (unless otherwise noted)



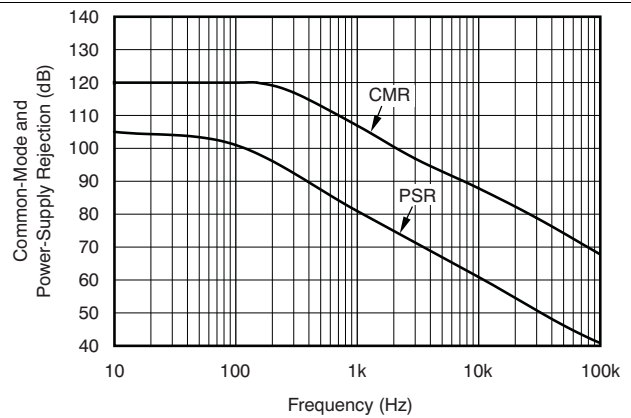
**Figure 1. Gain vs Frequency**



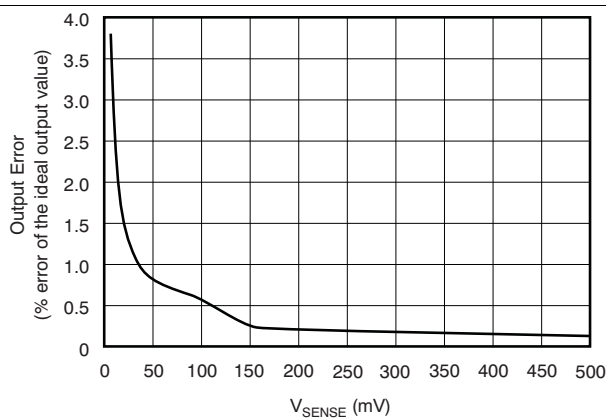
**Figure 2. Gain vs Frequency**



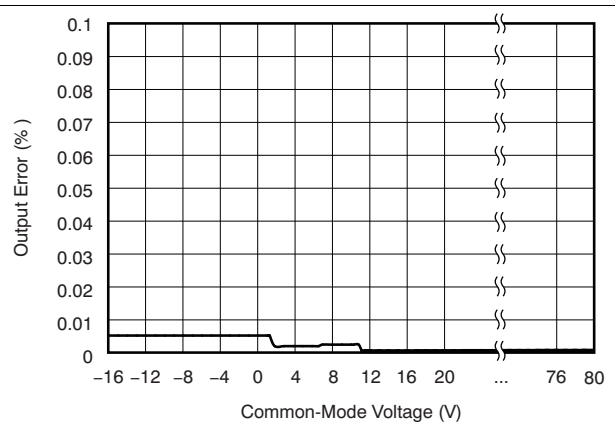
**Figure 3. Gain Plot**



**Figure 4. Common-Mode and Power-Supply Rejection vs Frequency**



**Figure 5. Output Error vs  $V_{SENSE}$**



**Figure 6. Output Error vs Common-Mode Voltage**





Typical Characteristics (continued)

At  $T_A = 25^\circ\text{C}$ ,  $V_S = 12\text{ V}$ ,  $V_{IN+} = 12\text{ V}$ , and  $V_{SENSE} = 100\text{ mV}$  (unless otherwise noted)

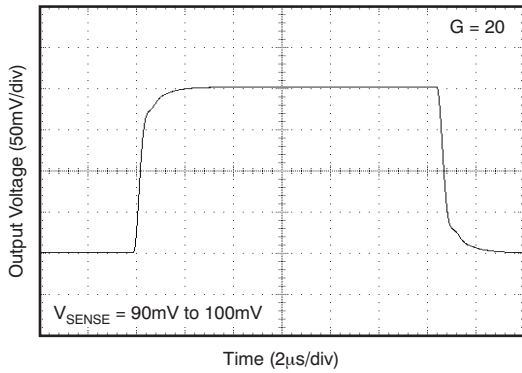


Figure 13. Step Response

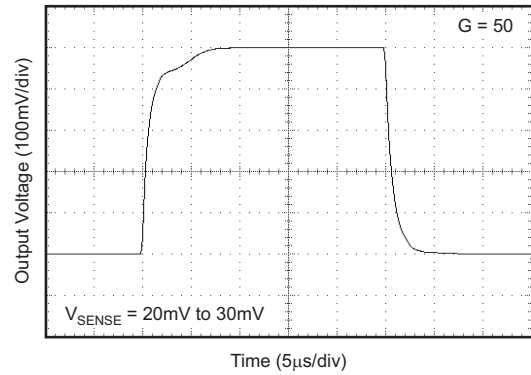


Figure 14. Step Response

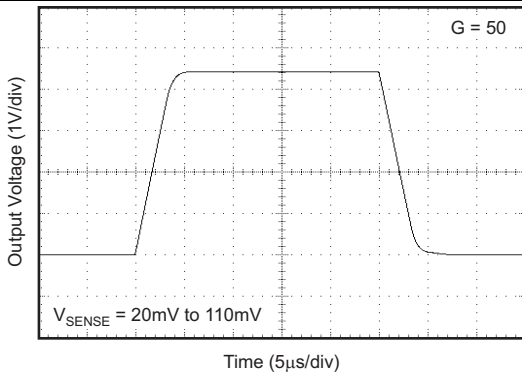


Figure 15. Step Response

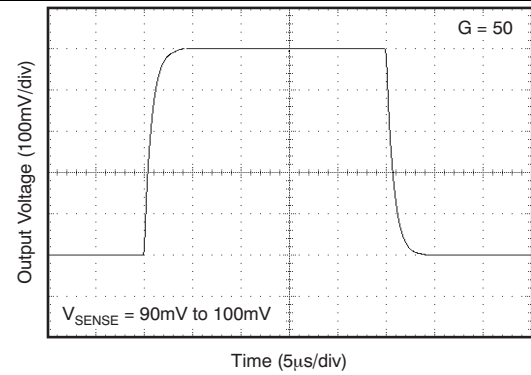


Figure 16. Step Response

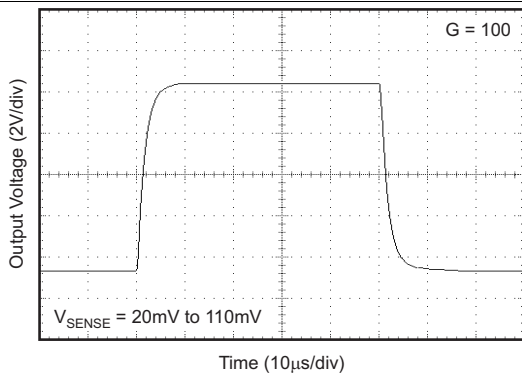


Figure 17. Step Response

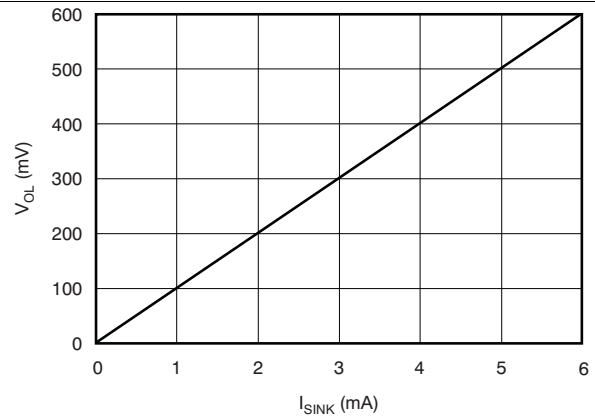


Figure 18. Comparator  $V_{OL}$  vs  $I_{SINK}$

### Typical Characteristics (continued)

At  $T_A = 25^\circ\text{C}$ ,  $V_S = 12\text{ V}$ ,  $V_{IN+} = 12\text{ V}$ , and  $V_{SENSE} = 100\text{ mV}$  (unless otherwise noted)

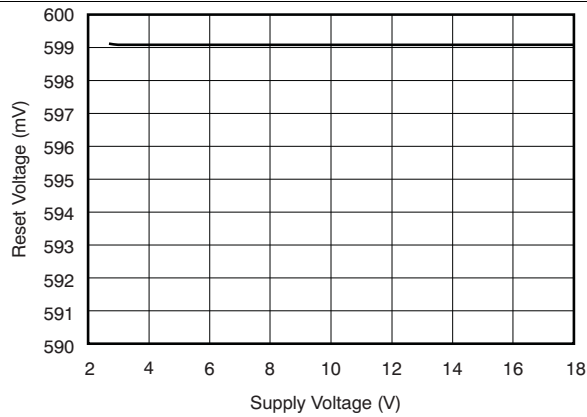


Figure 19. Comparator Trip Point vs Supply Voltage

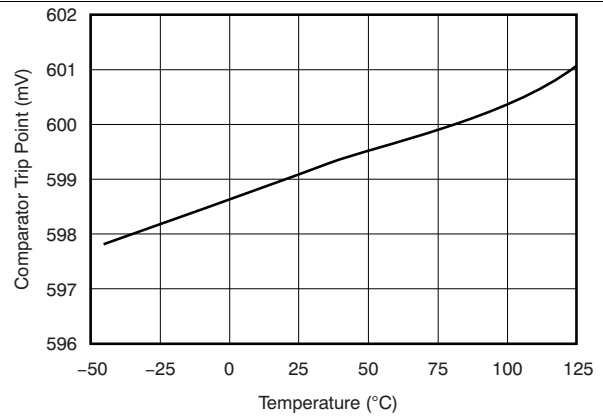


Figure 20. Comparator Trip Point vs Temperature

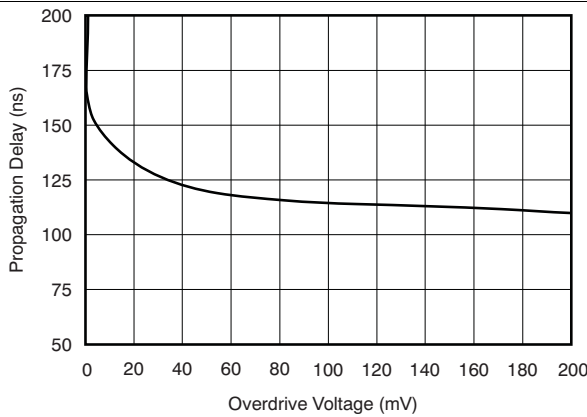


Figure 21. Comparator Propagation Delay vs Overdrive Voltage

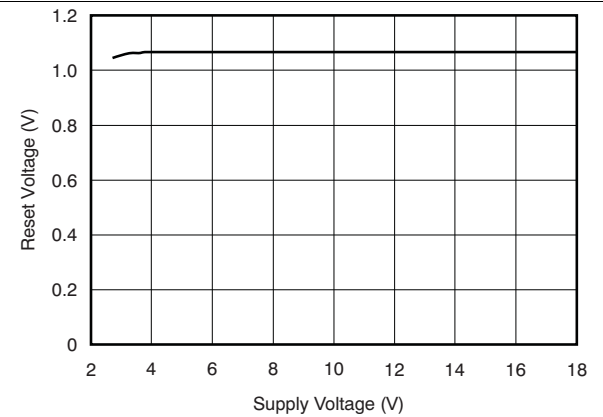


Figure 22. Comparator Reset Voltage vs Supply Voltage

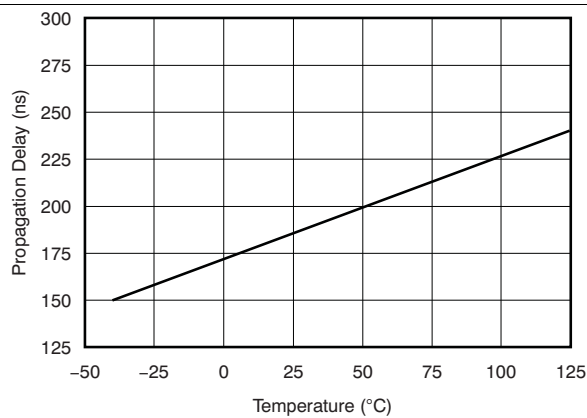


Figure 23. Comparator Propagation Delay vs Temperature

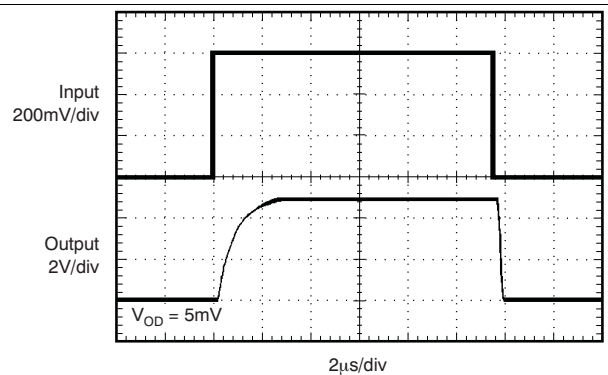
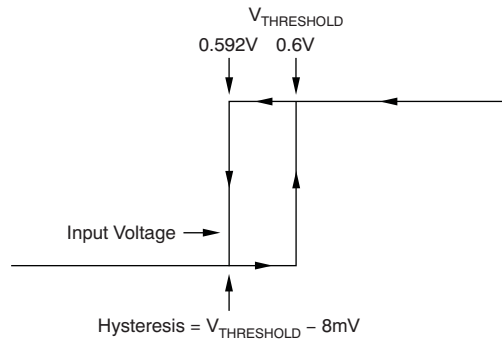


Figure 24. Comparator Propagation Delay

## 8 Parameter Measurement Information

### 8.1 Hysteresis

Figure 25 shows the typical comparator hysteresis.



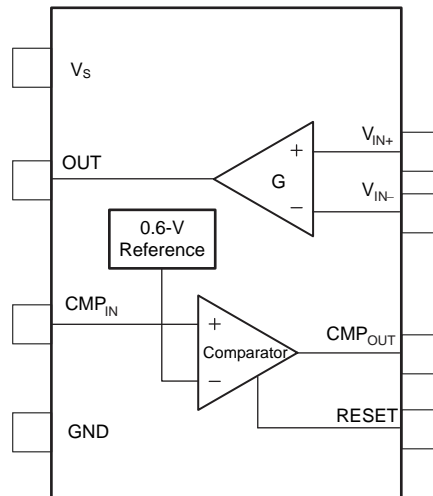
**Figure 25. Typical Comparator Hysteresis**

## 9 Detailed Description

### 9.1 Overview

The INA20x-Q1 current-shunt monitors operate over a wide common-mode voltage range ( $-16\text{ V}$  to  $+80\text{ V}$ ). These devices integrate an open-drain comparator with an internal  $0.6\text{-V}$  reference at the negative input. Use external dividers from the output of the current shunt monitor to the positive input of the comparator to set the positive input for overcurrent detection. The comparator includes a latching capability, but can also be made transparent by grounding (or floating) the RESET pin.

### 9.2 Functional Block Diagram



## 9.3 Feature Description

### 9.3.1 Comparator

The INA200-Q1, INA201-Q1, and INA202-Q1 devices incorporate an open-drain comparator. This comparator typically has 2 mV of offset and a 1.3  $\mu$ s (typical) response time. The  $\overline{\text{RESET}}$  pin latches and resets the output of the comparator; see [Figure 26](#).

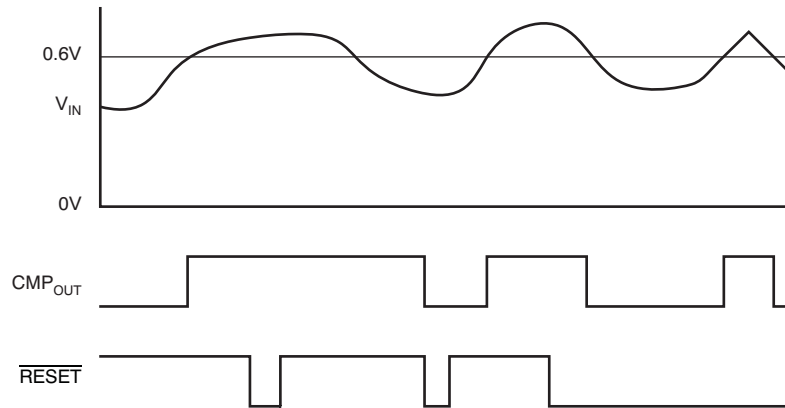


Figure 26. Comparator Latching Capability

### 9.3.2 Output Voltage Range

The output of the INA20x-Q1 is accurate within the output voltage swing range set by the power supply pin,  $V_S$ . Best illustration of this performance occurs when using the INA202-Q1 (gain-of-100 version), where a 100-mV full-scale input from the shunt resistor requires an output voltage swing of 10 V, and a power-supply voltage sufficient to achieve 10 V on the output.

## 9.4 Device Functional Modes

The INA20x-Q1 have a single functional mode and are operational when the power-supply voltage is greater than 2.7 V. The common-mode voltage must be between  $-16$  V and  $+80$  V. The maximum power supply voltage for the INA20x-Q1 is 18 V.

## 10 Application Information

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

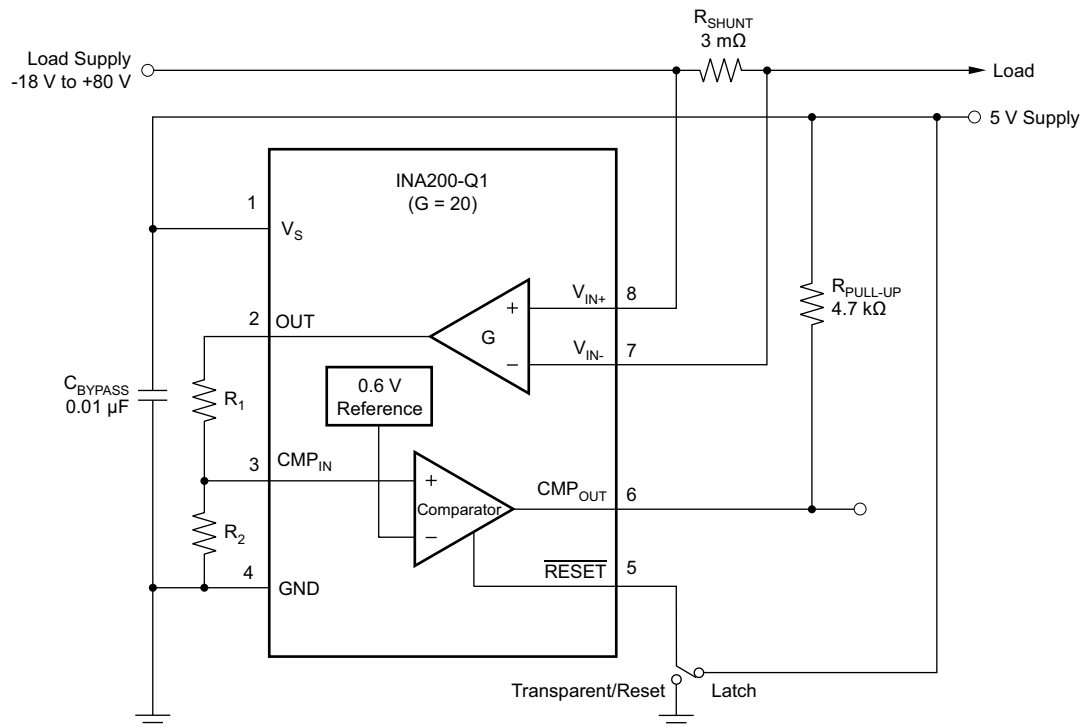
### 10.1 Application Information

The INA20x-Q1 series is designed to enable easy configuration for detecting overcurrent conditions and current monitoring in an application. This device is individually targeted towards overcurrent detection of a single threshold. However, this device can also be paired with additional devices and circuitry to create more complex monitoring functional blocks.

#### 10.1.1 Basic Connections

Figure 27 shows the basic connections of the INA200-Q1, INA201-Q1, and INA202-Q1. Connect the input pins,  $V_{IN+}$  and  $V_{IN-}$ , as close as possible to the shunt resistor to minimize any resistance in series with the shunt resistance.

Stability requires the use of power-supply bypass capacitors. Applications with noisy or high-impedance power supplies may require additional decoupling capacitors to reject power-supply noise. Connect bypass capacitors close to the device pins.



**Figure 27. INA200-Q1 Basic Connections**

#### 10.1.2 Selecting $R_S$

The value chosen for the shunt resistor,  $R_S$ , depends on the application and is a compromise between small-signal accuracy and maximum permissible voltage loss in the measurement line. High values of  $R_S$  provide better accuracy at lower currents by minimizing the effects of offset, whereas low values of  $R_S$  minimize voltage loss in the supply line. Most applications attain best performance with an  $R_S$  value that provides a full-scale shunt voltage range of 50 mV to 100 mV. Maximum input voltage for accurate measurements is 500 mV, but output voltage is limited by supply.

## Application Information (continued)

### 10.1.3 Input Filtering

An obvious and straightforward location for filtering is at the output of the INA20x-Q1 series; however, this location negates the advantage of the low output impedance of the internal buffer. The only other option for filtering is at the input pins of the INA20x-Q1, but the internal 5-k $\Omega$  + 30% input impedance complicates input filtering, as illustrated in Figure 28. Use the lowest possible resistor values to minimize both the initial shift in gain and effects of tolerance. Equation 1 gives the effect on initial gain:

$$\text{Gain Error \%} = 100 - \left( 100 \times \frac{5\text{k}\Omega}{5\text{k}\Omega + R_{\text{FILT}}} \right) \quad (1)$$

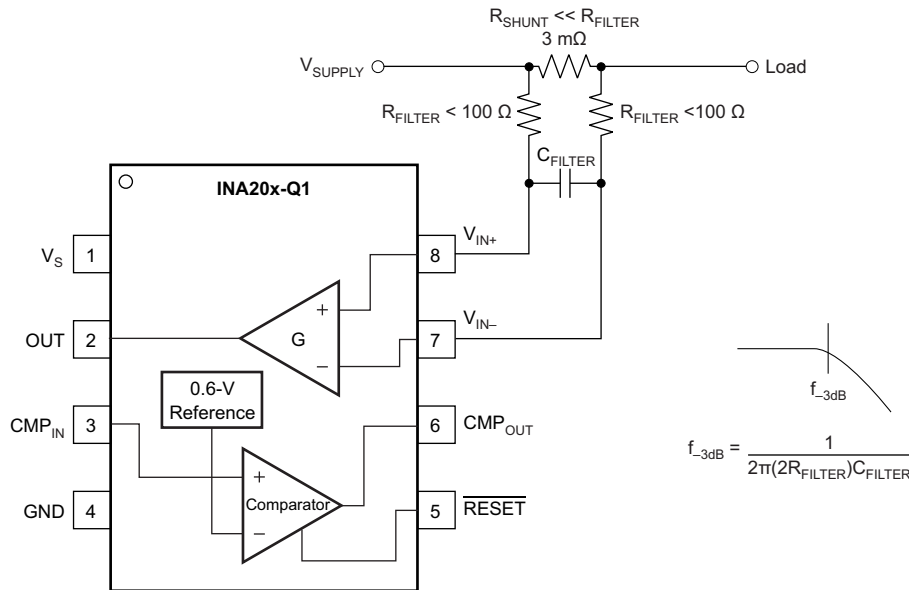


Figure 28. Input Filter

To calculate the total effect on gain error, replace the 5-k $\Omega$  term with 5 k $\Omega$  – 30%, (or 3.5 k $\Omega$ ) or 5 k $\Omega$  + 30% (or 6.5 k $\Omega$ ). One can also insert the tolerance extremes of  $R_{\text{FILT}}$  into the equation. If using a pair of 100- $\Omega$  1% resistors on the inputs, the initial gain error is 1.96%. Worst-case tolerance conditions always occur at the lower excursion of the internal 5-k $\Omega$  resistor (3.5-k $\Omega$ ), and the higher excursion of  $R_{\text{FILT}}$  + 3% in this case.

Note that one must then combine the specified accuracy of the INA20x-Q1 in addition to these tolerances. Although this discussion treated worst-case accuracy conditions by combining the extremes of the resistor values, it is appropriate to use geometric-mean or root-sum-square calculations to total the effects of accuracy variations.

### 10.1.4 Accuracy Variations as a Result of $V_{\text{SENSE}}$ and Common-Mode Voltage

The accuracy of the INA20x-Q1 current-shunt monitors is a function of two main variables:  $V_{\text{SENSE}}$  ( $V_{\text{IN}+} - V_{\text{IN}-}$ ) and common-mode voltage,  $V_{\text{CM}}$ , relative to the supply voltage,  $V_{\text{S}}$ . The expression for  $V_{\text{CM}}$  is  $(V_{\text{IN}+} + V_{\text{IN}-}) / 2$ ; however, in practice,  $V_{\text{CM}}$  is effectively the voltage at  $V_{\text{IN}+}$  because the voltage drop across  $V_{\text{SENSE}}$  is usually small.

This section addresses the accuracy of these specific operating regions:

- Normal Case 1:  $V_{\text{SENSE}} \geq 20$  mV,  $V_{\text{CM}} \geq V_{\text{S}}$
- Normal Case 2:  $V_{\text{SENSE}} \geq 20$  mV,  $V_{\text{CM}} < V_{\text{S}}$
- Low  $V_{\text{SENSE}}$  Case 1:  $V_{\text{SENSE}} < 20$  mV,  $-16$  V  $\leq V_{\text{CM}} < 0$
- Low  $V_{\text{SENSE}}$  Case 2:  $V_{\text{SENSE}} < 20$  mV,  $0$  V  $\leq V_{\text{CM}} \leq V_{\text{S}}$
- Low  $V_{\text{SENSE}}$  Case 3:  $V_{\text{SENSE}} < 20$  mV,  $V_{\text{S}} < V_{\text{CM}} \leq 80$  V

## Application Information (continued)

### 10.1.4.1 Normal Case 1: $V_{SENSE} \geq 20 \text{ mV}$ , $V_{CM} \geq V_S$

This region of operation provides the highest accuracy. Here, use of a two-step method characterizes and measures the input offset voltage. First, Equation 2 determines the gain.

$$G = \frac{V_{OUT1} - V_{OUT2}}{100\text{mV} - 20\text{mV}} \quad (2)$$

where:

$V_{OUT1}$  = output voltage with  $V_{SENSE} = 100 \text{ mV}$

$V_{OUT2}$  = output voltage with  $V_{SENSE} = 20 \text{ mV}$

Then the offset voltage is measured at  $V_{SENSE} = 100 \text{ mV}$  and referred to the input (RTI) of the current shunt monitor, as shown in Equation 3.

$$V_{OS\text{RTI}} \text{ (Referred-To-Input)} = \left[ \frac{V_{OUT1}}{G} \right] - 100\text{mV} \quad (3)$$

In the *Typical Characteristics*, Figure 6 (*Output Error versus Common-Mode Voltage* curve) shows the highest accuracy for the this region of operation. In this plot,  $V_S = 12 \text{ V}$ ; for  $V_{CM} \geq 12 \text{ V}$ , the output error is at its minimum. Using this case also creates the  $V_{SENSE} \geq 20 \text{ mV}$  output specifications in the *Electrical Characteristics: Current-Shunt Monitor* table.

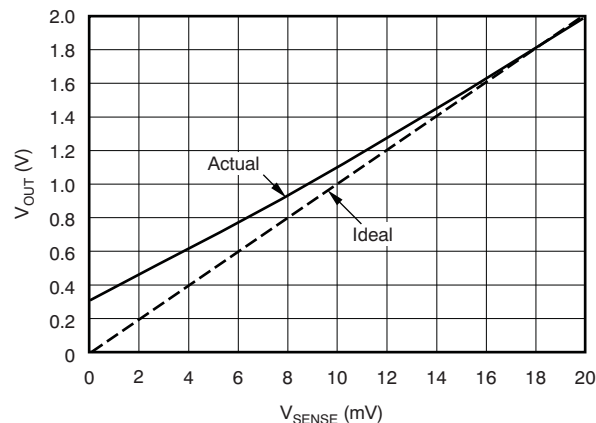
### 10.1.4.2 Normal Case 2: $V_{SENSE} \geq 20 \text{ mV}$ , $V_{CM} < V_S$

This region of operation has slightly less accuracy than Normal Case 1 as a result of the common-mode operating area in which the part functions, as seen in the Figure 6 (*Output Error versus Common-Mode Voltage* curve). As noted, for this graph  $V_S = 12 \text{ V}$ ; for  $V_{CM} < 12 \text{ V}$ , the output error increases as  $V_{CM}$  becomes less than  $12 \text{ V}$ , with a typical maximum error of 0.005% at the most negative  $V_{CM} = -16 \text{ V}$ .

### 10.1.4.3 Low $V_{SENSE}$ Case 1: $V_{SENSE} < 20 \text{ mV}$ , $-16 \text{ V} \leq V_{CM} < 0 \text{ V}$ ; and Low $V_{SENSE}$ Case 3: $V_{SENSE} < 20 \text{ mV}$ , $V_S < V_{CM} \leq 80 \text{ V}$

Although not designed for accurate operation in either of these regions, the INA20x-Q1 family of devices may have exposure to these conditions in some applications. For example, when monitoring power supplies being switched on and off with  $V_S$  still applied to the INA20x-Q1, it is important to know what the device behavior is in these regions.

As  $V_{SENSE}$  approaches 0 mV, in these  $V_{CM}$  regions, the device output accuracy degrades. A larger-than-normal offset can appear at the current shunt monitor output with a typical maximum value of  $V_{OUT} = 300 \text{ mV}$  for  $V_{SENSE} = 0 \text{ mV}$ . As  $V_{SENSE}$  approaches 20 mV,  $V_{OUT}$  returns to the expected output value with accuracy, as specified in the *Electrical Characteristics: Current-Shunt Monitor*. Figure 29 illustrates this effect using the INA202-Q1 (gain = 100).



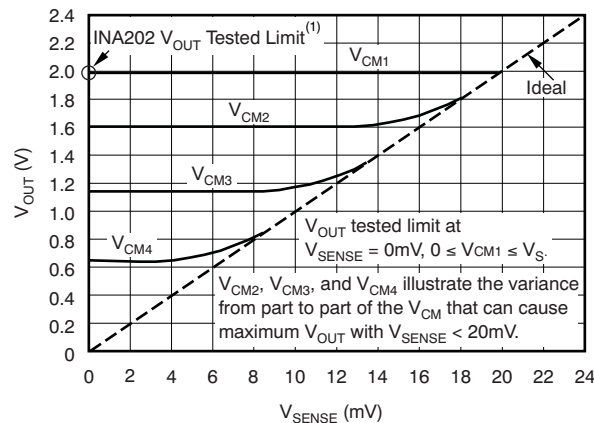
**Figure 29. Example for Low  $V_{SENSE}$  Cases 1 and 3 (INA202-Q1, Gain = 100)**



## Application Information (continued)

### 10.1.4.4 Low $V_{SENSE}$ Case 2: $V_{SENSE} < 20\text{ mV}$ , $0\text{ V} \leq V_{CM} \leq V_S$

This region of operation is the least accurate for the INA20x-Q1 family. To achieve the wide input common-mode voltage range, these devices use two op amp front ends in parallel. One op amp front end operates in the positive-input common-mode voltage range, and the other in the negative-input region. For this case, neither of these two internal amplifiers dominates, and overall loop gain is very low. Within this region,  $V_{OUT}$  approaches voltages close to linear operation levels for *normal case 2*. This deviation from linear operation becomes greatest the closer  $V_{SENSE}$  approaches 0 V. Within this region, as  $V_{SENSE}$  approaches 20 mV, device operation is closer to that described by *normal case 2*. Figure 30 illustrates this behavior for the INA202-Q1. To test the  $V_{OUT}$  maximum peak for this case, maintain a constant  $V_S$ , set  $V_{SENSE} = 0\text{ mV}$ , and sweep  $V_{CM}$  from 0 V to  $V_S$ . The exact  $V_{CM}$  at which  $V_{OUT}$  peaks during this test varies from part to part, but the tested  $V_{OUT}$  maximum peak for any part is less than the specified  $V_{OUT}$  test limit.



NOTE: (1) INA200  $V_{OUT}$  Tested Limit = 0.4V. INA201  $V_{OUT}$  Tested Limit = 1V.

Figure 30. Example for Low  $V_{SENSE}$  Case 2 (INA202-Q1, Gain = 100)

### 10.1.5 Transient Protection

The  $-16\text{-V}$  to  $+80\text{-V}$  common-mode range of the INA20X-Q1 is ideal for withstanding automotive fault conditions, ranging from 12-V battery reversal up to 80-V transients, because there is need for additional protective components up to those levels. In the event that the INA20x-Q1 are exposed to transients on the inputs in excess of their ratings, then external transient absorption with semiconductor transient absorbers (such as Zeners) is necessary. Do not use metal-oxide varistors (MOVs) or voltage-dependent resistors (VDRs) except when they are used in addition to a semiconductor transient absorber. Select the transient absorber such that it never allows exposure of the INA20X-Q1 to transients greater than 80 V (that is, allow for transient absorber tolerance, as well as additional voltage due to transient absorber dynamic impedance). Despite the use of internal zener-type ESD protection, the INA20x-Q1 do not lend themselves to using external resistors in series with the inputs, because the internal gain resistors can vary up to  $\pm 30\%$ . (If gain accuracy is not important, then one can add resistors in series with the INA20x-Q1 inputs with two equal resistors on each input.)



### 10.2.1.2 Detailed Design Procedure

Figure 31 shows the basic connections for a low-side, switch overcurrent shutdown application. Connect input pins IN+ and IN– as close as possible to the current-sensing resistor (R<sub>SHUNT</sub>) to minimize any resistance in series with the shunt resistance. Additional resistance between the current-sensing resistor and input pins can result in errors in the measurement. When input current flows through this external input resistance, the voltage developed across the shunt resistor can differ from the voltage reaching the input pins. Connect the input pins to one of the three shunt options shown in Figure 31.

Use the device gain and shunt resistor value to calculate the OUT pin voltage, V<sub>OUT\_TRIP</sub>, for the desired trip current, as shown in Equation 4:

$$V_{OUT\_TRIP} = I_{TRIP} \times R_{SHUNT} \times \text{Gain}$$

where

- I<sub>TRIP</sub> = Desired trip current
  - R<sub>SHUNT</sub> = Shunt resistor value
- (4)

Configure R<sub>1</sub> and R<sub>2</sub> so that the current trip point is equal to the 0.6-V reference voltage, as shown in Equation 5:

$$(R_2 / (R_1 + R_2)) \times V_{OUT\_TRIP} = 0.6 \text{ V}$$

(5)

### 10.2.1.3 Application Curves

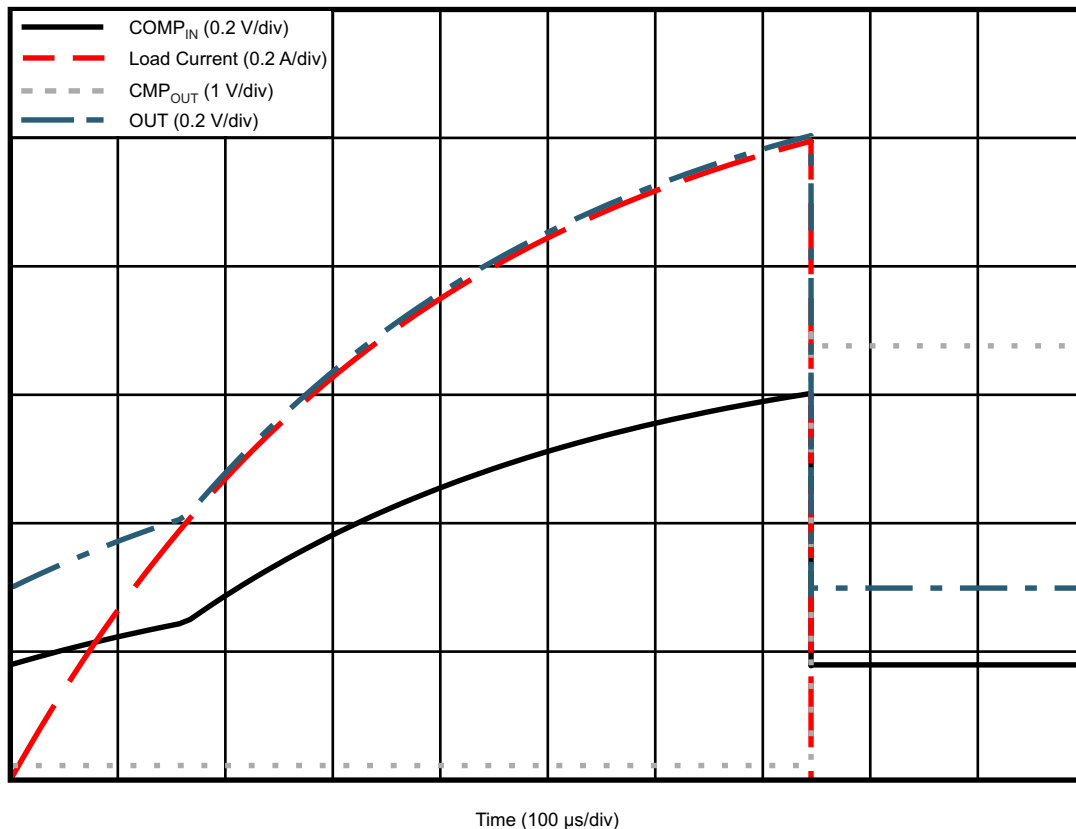
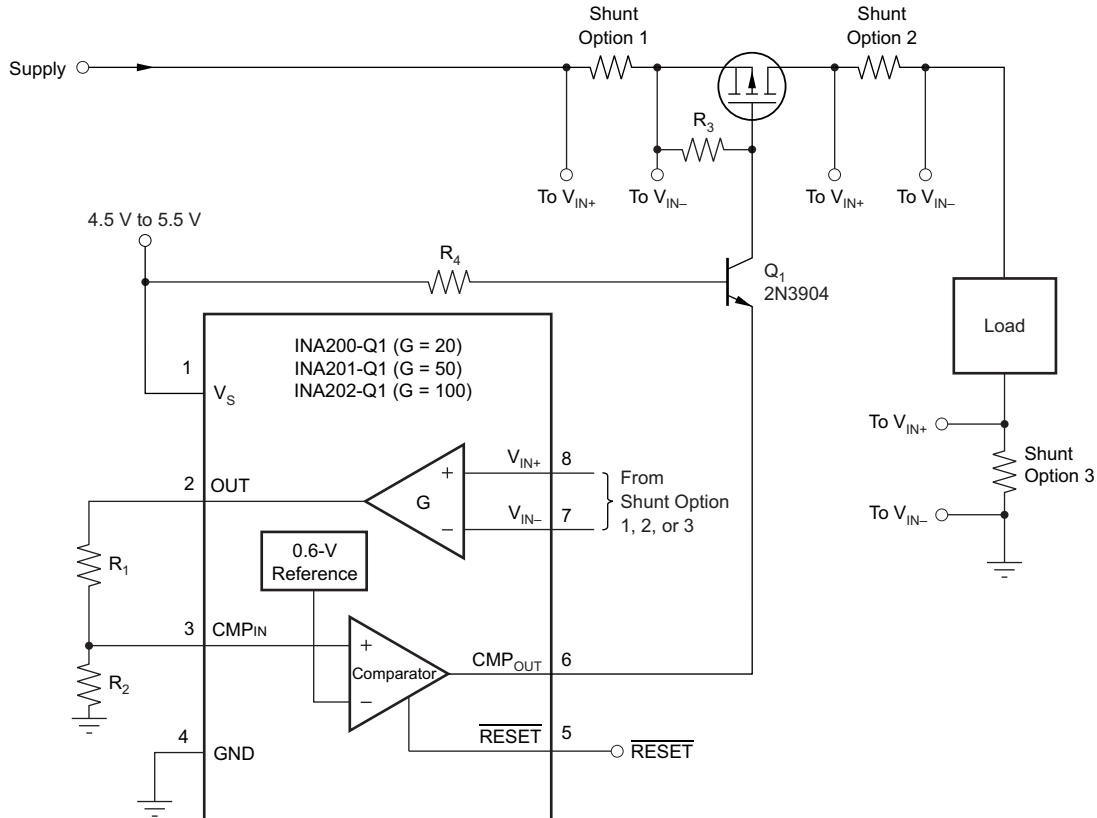


Figure 32. Low-Side Switch Overcurrent Shutdown Response

### 10.2.2 High-Side Switch Overcurrent Shutdown

Figure 33 shows the basic connection for a high-side, switch overcurrent shutdown application. The high-side PMOS switch disconnects when an overcurrent event occurs. The previous [Detailed Design Procedure](#) section describes how to apply this application example. The difference is that the current is sensed on the high side of the bus in this application, and the low side of the bus in the previous application example.

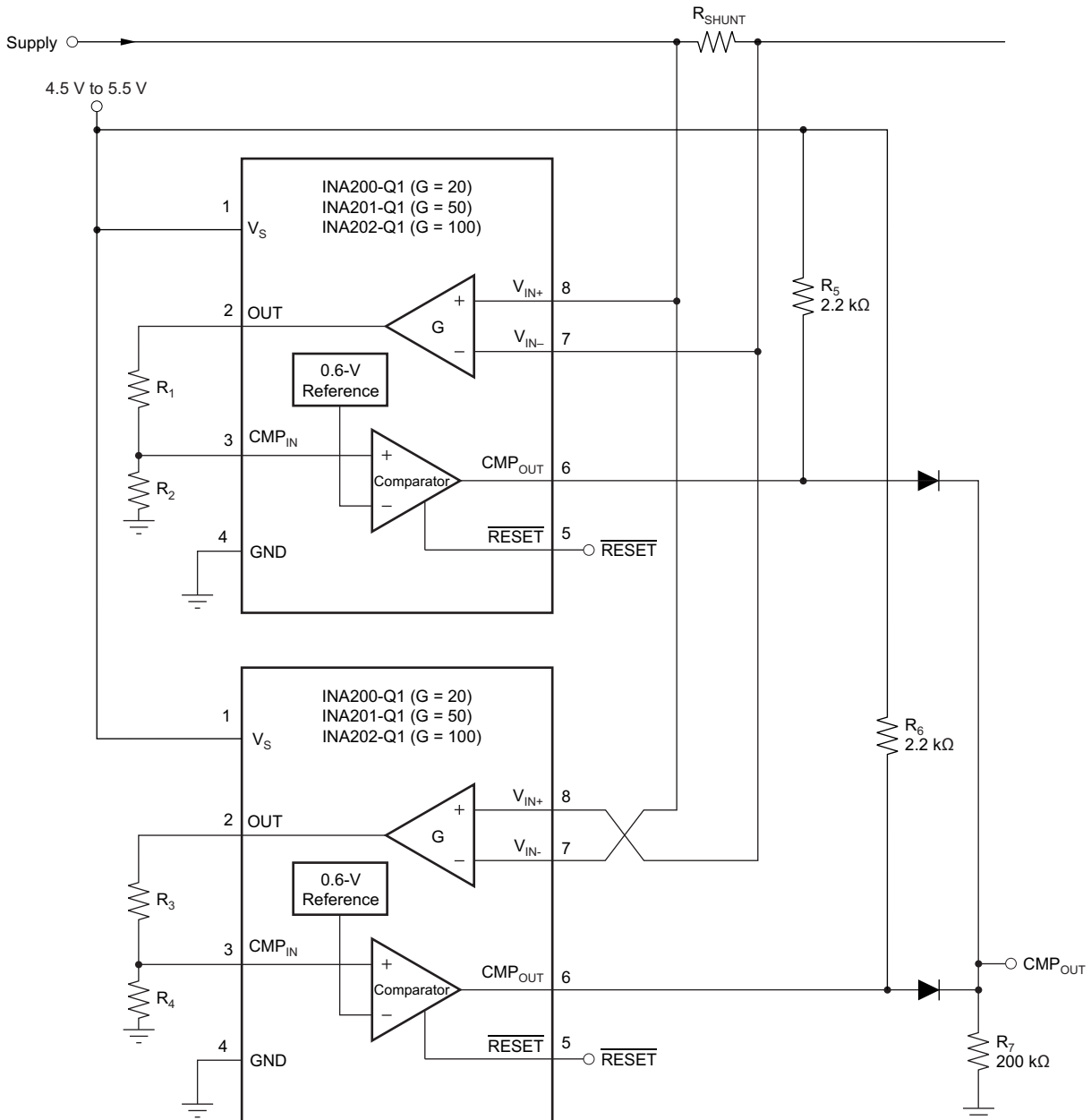


NOTE: Q cascodes the comparator output to drive a high-side FET (the 2N3904 shown is good up to 60 V). The shunt can be located in any one of the three locations shown. Use the latching capability in shutdown applications to prevent oscillation at the trip point.

**Figure 33. High-Side Switch Overcurrent Shutdown**

### 10.2.3 Bidirectional Overcurrent Comparator

Figure 34 shows the basic connection for a bidirectional overcurrent comparator using two INA20x-Q1 devices of the same gain.



NOTE: It is possible to set different limits for each direction.

**Figure 34. Bidirectional Overcurrent Comparator**

## 11 Power Supply Recommendations

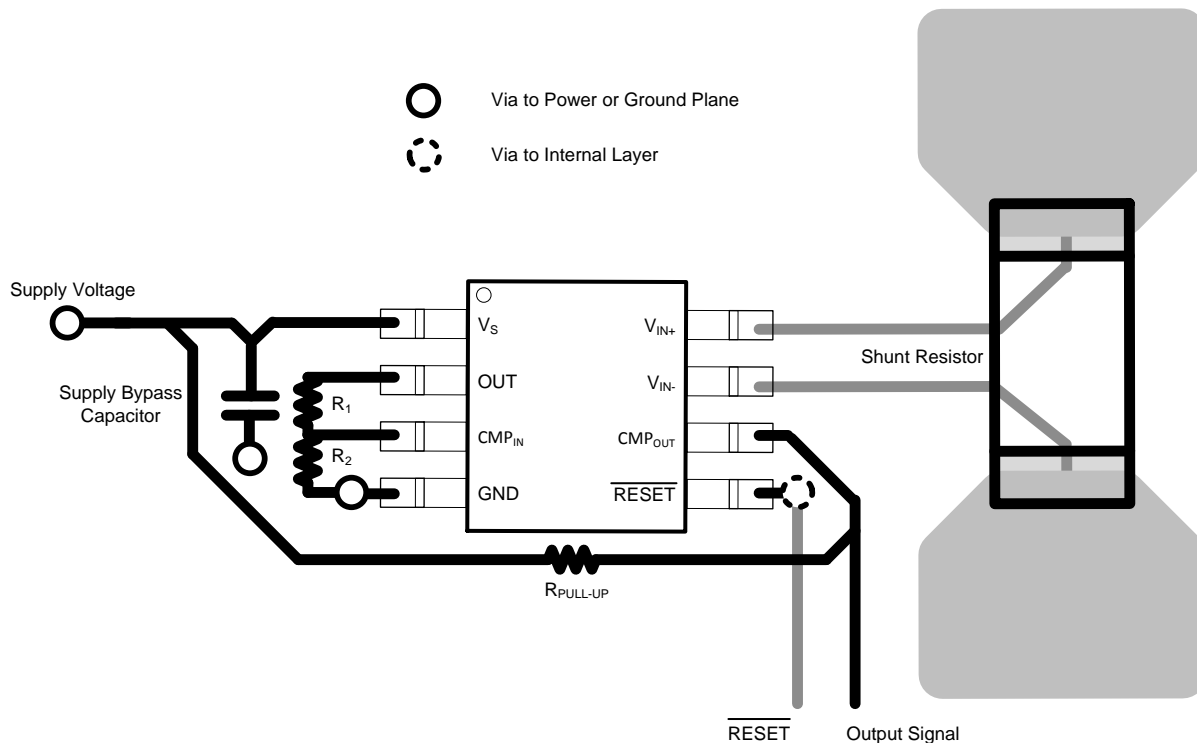
The input circuitry of the INA20x-Q1 accurately measures beyond the power-supply voltage,  $V_S$ . For example, the  $V_S$  power supply can be 5 V, whereas the load power-supply voltage goes up to 80 V. However, the voltages on the power-supply pins limit the output voltage range of the OUT pin.

## 12 Layout

### 12.1 Layout Guidelines

- Connect the input pins to the sensing resistor using a Kelvin or four-wire connection. This connection technique makes sure that only the current-sensing resistor impedance is detected between the input pins. Poor routing of the current-sensing resistor commonly results in additional resistance present between the input pins. Given the very low ohmic value of the current resistor, any additional high-current carrying impedance can cause significant measurement errors.
- Place the power-supply bypass capacitor as close as possible to the supply and ground pins. The recommended value of this bypass capacitor is 0.1  $\mu\text{F}$ . Add additional decoupling capacitance to compensate for noisy or high-impedance power supplies.

### 12.2 Layout Example



**Figure 35. INA20x-Q1 Layout Example**

## 13 デバイスおよびドキュメントのサポート

### 13.1 関連リンク

表 2 に、クイック・アクセス・リンクの一覧を示します。カテゴリには、技術資料、サポートおよびコミュニティ・リソース、ツールとソフトウェア、およびサンプル注文またはご購入へのクイック・アクセスが含まれます。

表 2. 関連リンク

製品	プロダクト・フォルダ	サンプルとご購入	技術資料	ツールとソフトウェア	サポートとコミュニティ
INA200-Q1	<a href="#">ここをクリック</a>	<a href="#">ここをクリック</a>	<a href="#">ここをクリック</a>	<a href="#">ここをクリック</a>	<a href="#">ここをクリック</a>
INA201-Q1	<a href="#">ここをクリック</a>	<a href="#">ここをクリック</a>	<a href="#">ここをクリック</a>	<a href="#">ここをクリック</a>	<a href="#">ここをクリック</a>
INA202-Q1	<a href="#">ここをクリック</a>	<a href="#">ここをクリック</a>	<a href="#">ここをクリック</a>	<a href="#">ここをクリック</a>	<a href="#">ここをクリック</a>

### 13.2 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 13.3 商標

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All other trademarks are the property of their respective owners.

### 13.4 静電気放電に関する注意事項



すべての集積回路は、適切なESD保護方法を用いて、取扱いと保存を行うようにして下さい。

静電気放電はわずかな性能の低下から完全なデバイスの故障に至るまで、様々な損傷を与えます。高精度の集積回路は、損傷に対して敏感であり、極めてわずかなパラメータの変化により、デバイスに規定された仕様に適合しなくなる場合があります。

### 13.5 Glossary

**SLYZ022** — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 14 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスについて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
INA200AQDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU   NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	SHZ	<a href="#">Samples</a>
INA201AQDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	Call TI   NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	QWV	<a href="#">Samples</a>
INA202AQDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	SIA	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF INA200-Q1, INA201-Q1, INA202-Q1 :**

- Catalog : [INA200](#), [INA201](#), [INA202](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

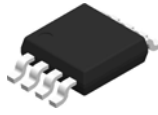
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA200AQDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA201AQDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA202AQDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA200AQDGKRQ1	VSSOP	DGK	8	2500	366.0	364.0	50.0
INA201AQDGKRQ1	VSSOP	DGK	8	2500	366.0	364.0	50.0
INA202AQDGKRQ1	VSSOP	DGK	8	2500	366.0	364.0	50.0

# DGK0008A



# PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4214862/A 04/2023

**NOTES:**

PowerPAD is a trademark of Texas Instruments.

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

# EXAMPLE BOARD LAYOUT

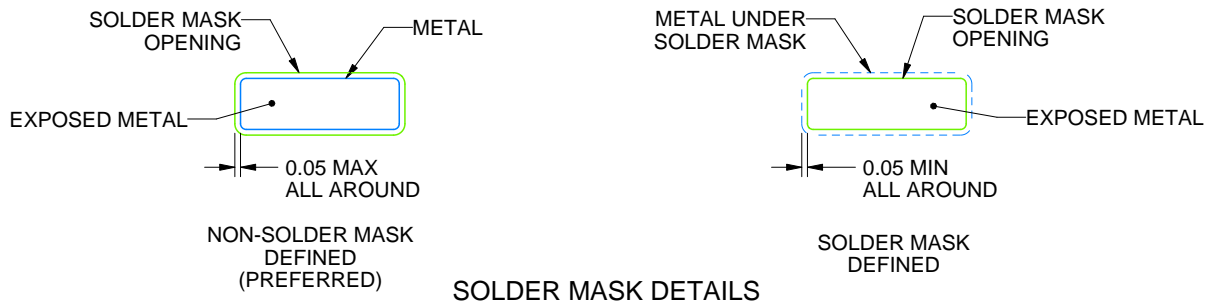
DGK0008A

™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 15X



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

# EXAMPLE STENCIL DESIGN

DGK0008A

<sup>TM</sup> VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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